SBS818

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Schottky Barrier Diode

30V, 2A, Low VF, Non-Monolithic Dual EMH8 Common Cathode

Applications

· High frequency rectification (switching regulators, converters, choppers)

Features

- · Low switching noise
- Low forward voltage (IF=2.0A, VF max=0.52V)
- Ultrasmall package permitting applied sets to be small and slim (Mounting height 0.75mm)

Specifications

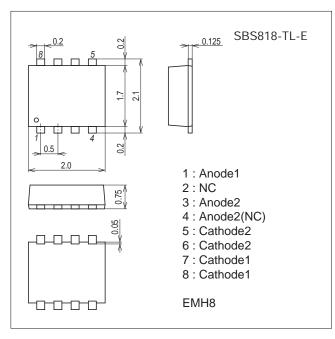
Absolute Maximum Ratings at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		30	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		30	V
Average Output Current	IO	When mounted on ceramic substrate (900mm ² ×0.8mm)	2.0	Α
		When mounted on glass epoxy substrate (0.96mm ² ×0.03mm)	1.5	Α
Surge Forward Current	I _{FSM}	50Hz sine wave, 1 cycle	20	Α
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit: mm (typ) 7045-004



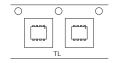
Product & Package Information

• Package : EMH8

• JEITA, JEDEC

• Minimum Packing Quantity : 3,000 pcs./reel

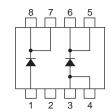
Packing Type: TL



Marking



Electrical Connection



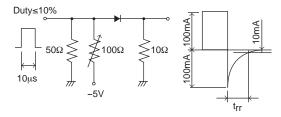
*: Terminal 4 is used for the purposes such as test. Although it is connected to Anode 2, please handle it as NC Terminal.

Electrical Characteristics at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	UIIIL	
Reverse Voltage	VR	I _R =1mA	30			V	
	V _F 1	IF=1.0A		0.37	0.42	V	
Forward Voltage	V _F 2	IF=1.5A		0.42	0.47	V	
	V _F 3	IF=2.0A		0.46	0.52	V	
Reverse Current	IR	V _R =15V			350	μΑ	
Interterminal Capacitance	С	V _R =10V, f-1MHz		30		pF	
Reverse Recovery Time	t _{rr}	I _F =I _R =100mA, See specified Test Circuit.			10	ns	
	Rth(j-a)1	When mounted in Cu-foiled area of		100		°C / W	
Thermal Resistance		900mm ² ×0.8mm on glass epoxy substrate				C/W	
	Rth(j-a)2	When mounted on ceramic substrate (900mm ² ×0.8mm)		65		°C / W	

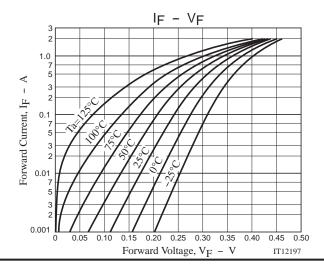
^{*:} The absolute maximum ratings and electrical characteristics refer to those between Terminal 1 and Terminal 7 (or 8), and between Terminal 3 and Terminal 5 (or 6).

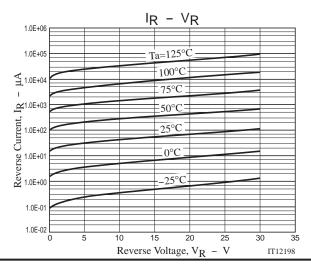
trr Test Circuit

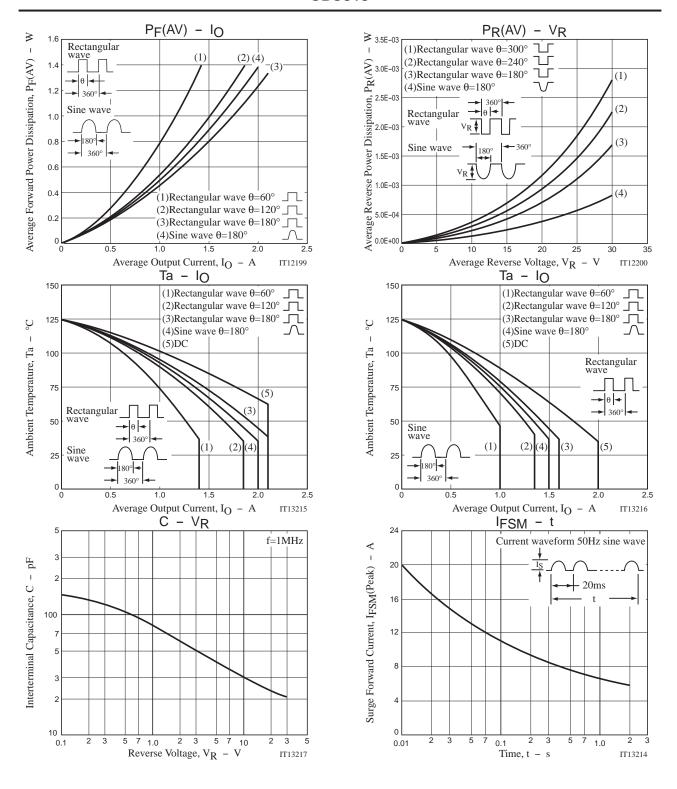


Ordering Information

Device	Package	Shipping	memo	
SBS818-TL-E	EMH8	3,000pcs./reel	Pb Free	





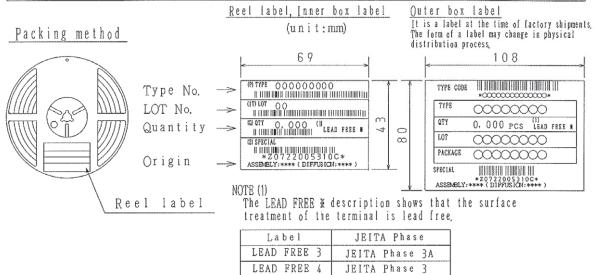


Embossed Taping Specification

SBS818-TL-E

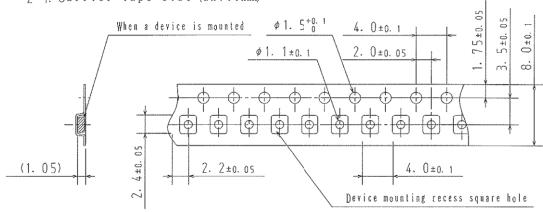
1. Packing Format

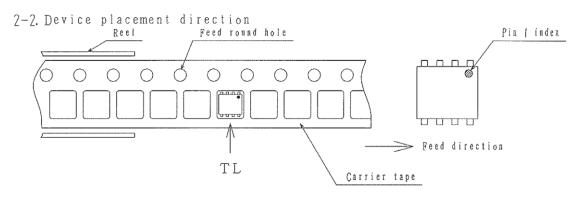
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
EMH8	MCP4	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained	
Sandan Sanda						Dimensions:mm (external)	
					183×72×185	440×195×210	



2. Taping configuration

7-1. Carrier tape size (unit:mm)

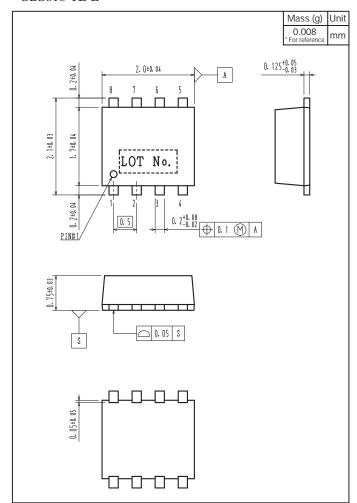




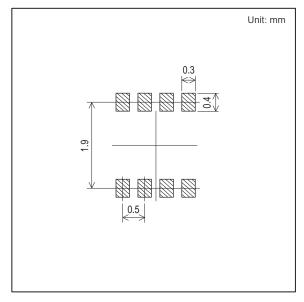
Those with pin | index on the feed hole side·····TL

Outline Drawing

SBS818-TL-E



Land Pattern Example



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